



1.5A High Efficient Rectifier

Features

1. High surge current capability
2. High reliability
3. Low forward voltage drop
4. High current capability



Absolute Maximum Ratings

T_j=25°C

Parameter	Test Conditions	Type	Symbol	Value	Unit
Repetitive peak reverse voltage = Working peak reverse voltage = DC blocking voltage		HER151	V _{RRM}	50	V
		HER152	=V _{RWM}	100	V
		HER153	=V _R	200	V
		HER154		300	V
		HER155		400	V
		HER156		600	V
		HER157		800	V
		HER158		1000	V
Peak forward surge current			I _{FSM}	50	A
Average forward current	T _A =55°C		I _{FAV}	1.5	A
Storage temperature range			T _{stg}	-65~+175	°C

Electrical Characteristics

T_j=25°C

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	I _F =1.5A	HER151-HER154	V _F			1.0	V
		HER155	V _F			1.3	V
		HER156-HER158	V _F			1.85	V
Reverse current	T _A =25°C		I _R			5	μA
	T _A =100°C		I _R			100	μA
Maximum reverse recovery time	I _F =0.5A, I _R =1.0A, I _{rr} =0.25A	HER151~HER155	T _{rr}			50	ns
		HER156~HER158	T _{rr}			70	ns
Diode capacitance	V _R =4V, f=1MHz		C _D		30		pF

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Characteristics ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

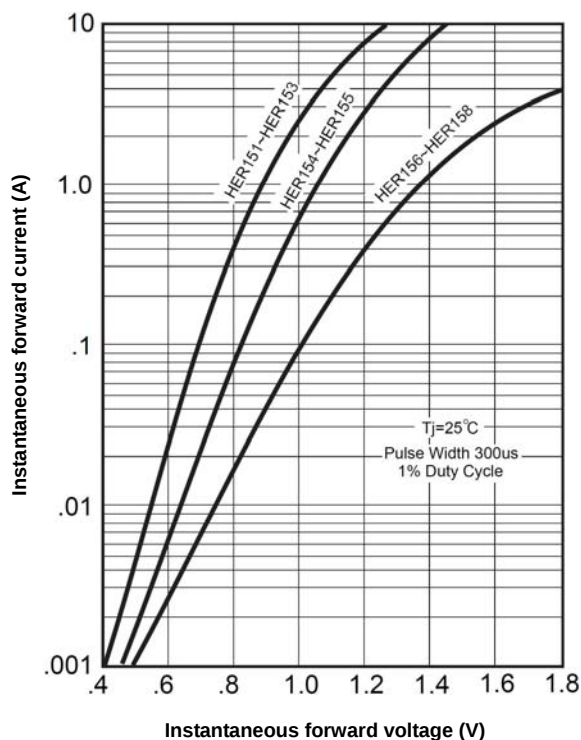


Figure 1. Typical forward characteristics

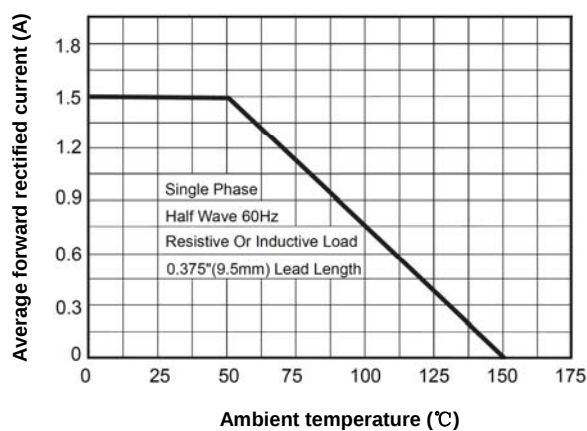


Figure 2. Forward derating curve

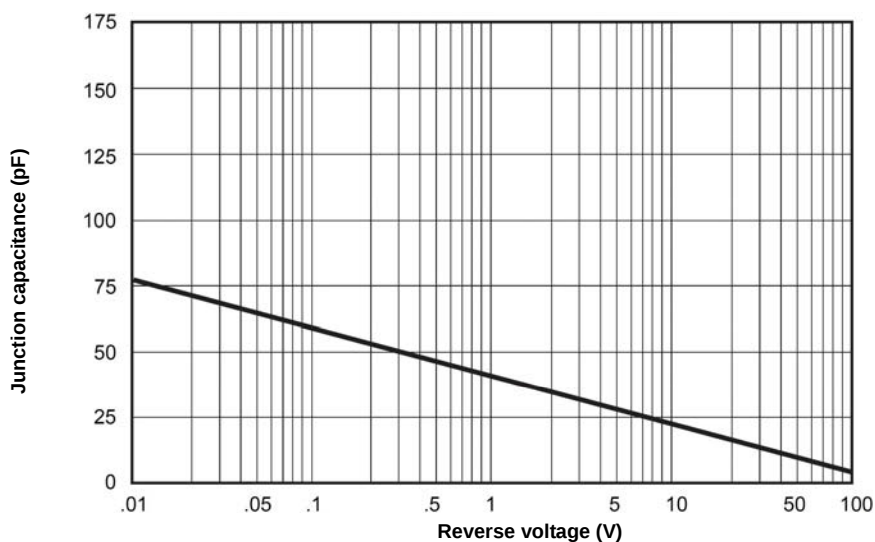
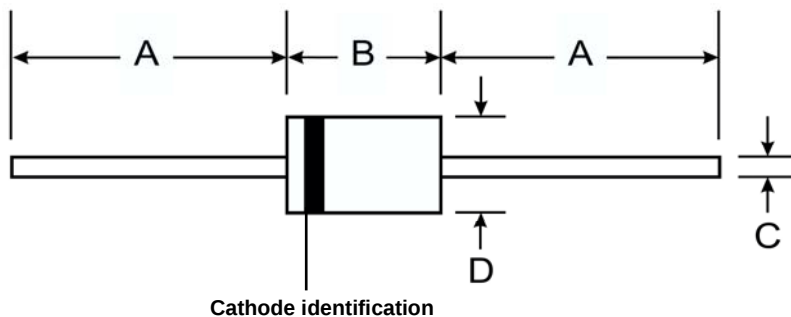


Figure 3. Junction capacitance

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Dimensions in mm



DIM	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	1.000	---	25.40	---
B	0.230	0.300	5.80	7.60
C	0.026	0.034	0.70	0.90
D	0.104	0.140	2.60	3.60

Case: molded plastic DO-15

Polarity: cathode band

Marking: type number

Marking

